## NSN 5961-01-391-7995

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-391-7995 **Inclosure Material:** Metal **Overall Length:** Between 2.140 inches and 2.785 inches Overall Diameter: Between 0.085 inches and 0.140 inches **Function For Which Designed:** Transient suppressor **Mounting Method:** Terminal **Features Provided:** Quality assurance level txv **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 76.0 working peak reverse voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 1.00 milliamperes forward current, average peak **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/516 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: